NSN 5962-01-135-2105

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Body Leng	
1.310 inche	
Body Widtl	
0.600 inche	
Body Heigl	
0.052 inche	
	Power Dissipation Rating:
400.0 milliw	
	Tempurature Range:
	degrees celsius
	mpurature Range:
	0 degrees celsius
End Applic	
Training dev	
Features P	
	/ sealed and programmable and expandable and wire-or outputs and w/enable
Inclosure N	
Ceramic an	-
Inclosure C	Configuration:
Dual-in-line	
Output Log	jic Form:
Transistor-t	ransistor logic
Input Circu	it Pattern:
8 input	
Terminal S	urface Treatment:
Solder	
Voltage Ra	ting And Type Per Characteristic:
-1.5 volts p	ower source and 5.5 volts power source
Time Ratin	g Per Chacteristic:
75.00 nanos	seconds propagation delay time, low to high level output
Memory De	evice Type:
Rom	
Memory Ca	pacity:
Unknown	
Terminal T	ype And Quantity:
24 printed c	ircuit
Shelf Life:	
N/a	
Unit Of Mea	asure:
 Demilitariza	ation
	imli

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